

HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

MAIN PRODUCT CHARACTERISTICS

| | |
|----------------------|----------|
| $I_{F(AV)}$ | 2 x 10 A |
| V_{RRM} | 200 V |
| $T_j(\text{max})$ | 150 °C |
| $V_F(\text{max})$ | 0.85 V |
| $t_{rr}(\text{max})$ | 25 ns |

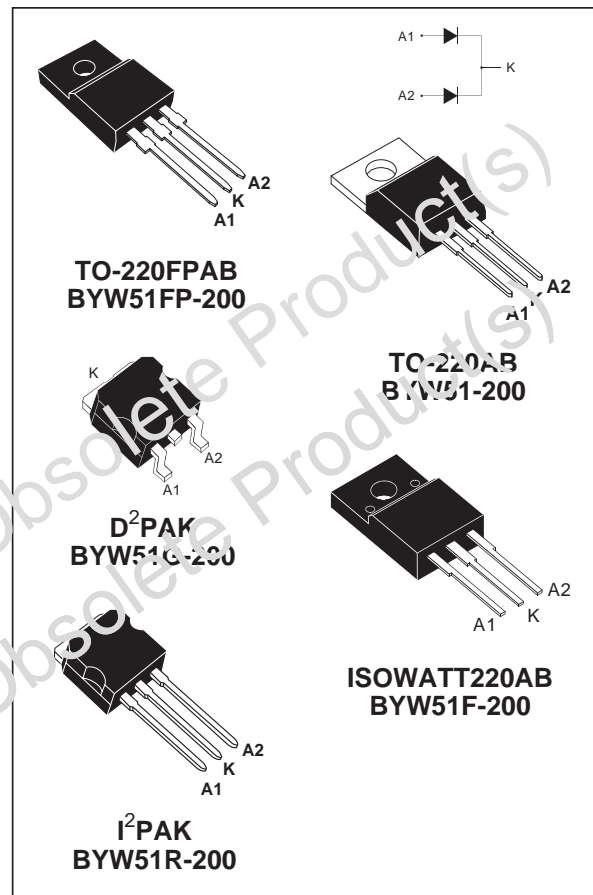
FEATURES AND BENEFITS

- SUITED FOR SMPS
- VERY LOW FORWARD LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- HIGH SURGE CURRENT CAPABILITY
- INSULATED PACKAGES (ISOWATT220AB / TO-220FP):
Insulation voltage = 2000 V DC
Capacitance = 12 pF

DESCRIPTION

Dual center tap rectifier suited for Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in TO-220AB, ISOWATT220AB, TO-220FP, D²PAK or I²PAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values, per diode)

| Symbol | Parameter | | Value | Unit | | |
|--------------|---|--|--------------------------------|------------|----|---|
| V_{RRM} | Repetitive peak reverse voltage | | 200 | V | | |
| $I_{F(RMS)}$ | RMS forward current | | 20 | A | | |
| $I_{F(AV)}$ | Average forward current $\delta = 0.5$ | TO-220AB / D ² PAK / I ² PAK | $T_c = 120^\circ\text{C}$ | Per diode | 10 | A |
| | | | | Per device | 20 | |
| | | ISOWATT220AB | $T_c = 95^\circ\text{C}$ | Per diode | 10 | |
| | | | | Per device | 20 | |
| | | TO-220FPAB | $T_c = 85^\circ\text{C}$ | Per diode | 10 | |
| | | | | Per device | 20 | |
| I_{FSM} | Surge non repetitive forward current | | $t_p = 10\text{ms}$ sinusoidal | 100 | A | |
| T_{stg} | Storage temperature range | | - 65 to + 150 | °C | | |
| T_j | Maximum operating junction temperature | | 150 | °C | | |

BYW51/F/G/FP/R-200

THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit | |
|----------------------|------------------|--|-----------|------|------|
| R _{th(j-c)} | Junction to case | TO-220AB / D ² PAK / I ² PAK | Per diode | 2.5 | °C/W |
| | | | Total | 1.4 | |
| | | ISOWATT220AB | Per diode | 5.1 | |
| | | | Total | 4.05 | |
| | | TO-220FPAB | Per diode | 5.7 | |
| | | | Total | 4.6 | |
| R _{th(c)} | Coupling | TO-220AB / D ² PAK / I ² PAK | 0.25 | °C/W | |
| | | ISOWATT220AB | 3.0 | | |
| | | TO-220FPAB | 3.5 | | |

When diodes 1 and 2 are used simultaneously :

$$\Delta T_c (\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

STATIC ELECTRICAL CHARACTERISTICS (Per diode)

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|-------------------|-------------------------|-------------------------|-----------------------------------|------|------|------|------|
| I _R * | Reverse leakage current | T _j = 25 °C | V _R = V _{RRM} | | | 15 | μA |
| | | T _j = 100 °C | | | | 1 | mA |
| V _F ** | Forward voltage drop | T _j = 125 °C | I _F = 8 A | | | 0.85 | V |
| | | T _j = 125 °C | I _F = 16 A | | | 1.05 | |
| | | T _j = 25 °C | I _F = 16 A | | | 1.15 | |

Pulse test : * t_p = 5 ms, δ = 2 %

** t_p = 380 μs, δ = 2 %

To evaluate the conduction losses use the following equation :

$$P = 0.65 \times I_{E(AV)} + 0.025 \times I_{F(RMS)}^2$$

RECOVERY CHARACTERISTICS

| Symbol | Test Conditions | | | Typ. | Max. | Unit |
|-----------------|------------------------|---|-------------------------------|------|------|------|
| trr | T _j = 25 °C | I _F = 0.5A I _R = 1A | I _{rr} = 0.25A | | 25 | ns |
| | | I _F = 1A V _R = 30V | dI _F /dt = -50A/μs | | 35 | |
| tfr | T _j = 25 °C | I _F = 1A V _{FR} = 1.1 x V _F max | dI _F /dt = -50A/μs | 15 | | ns |
| V _{FP} | T _j = 25 °C | I _F = 1A | dI _F /dt = -50A/μs | 2 | | V |

Fig. 1: Average forward power dissipation versus average forward current (per diode).

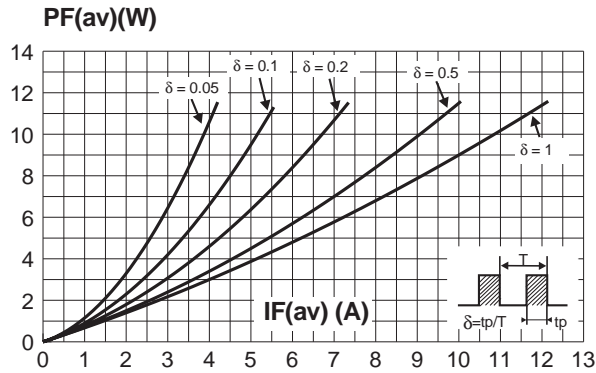


Fig. 2: Peak current versus form factor (per diode).

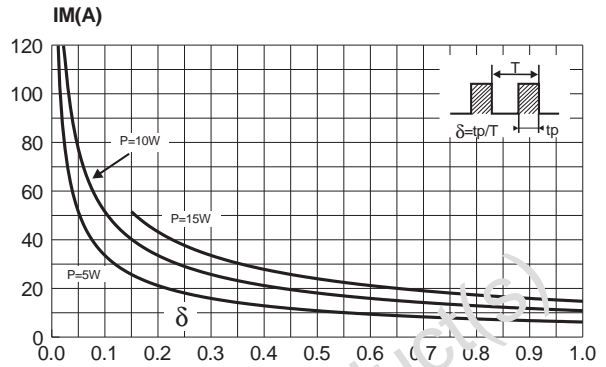


Fig. 3-1: Average forward current versus ambient temperature ($\delta = 0.5$, D²PAK, TO-220AB).

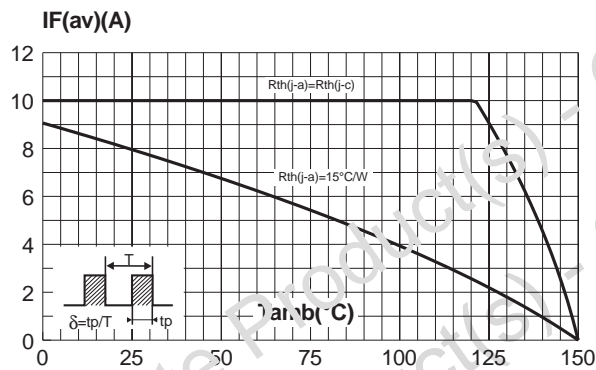


Fig. 3-2: Average forward current versus ambient temperature ($\delta = 0.5$, ISOWATT220AB, TO-220FPAL).

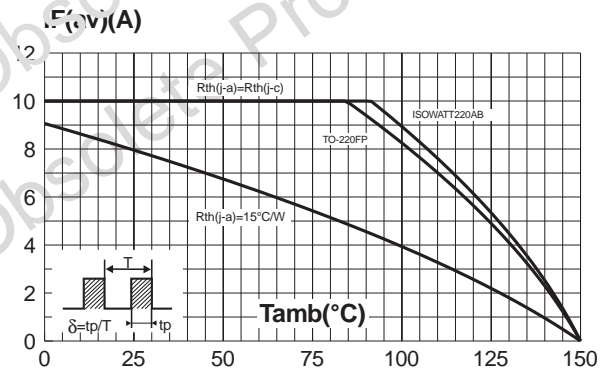


Fig. 4-1: Non repetitive surge peak forward current versus overload duration (D²PAK, TO-220AB).

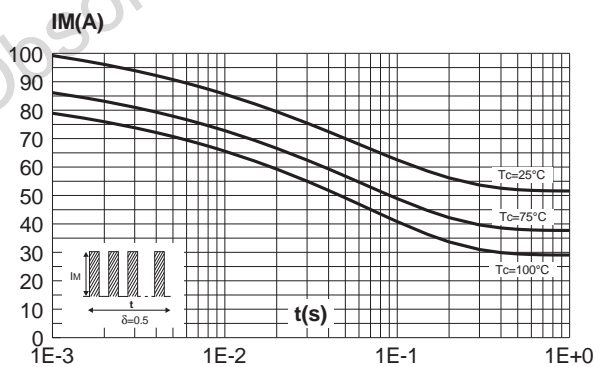


Fig. 4-2: Non repetitive surge peak forward current versus overload duration (ISOWATT220AB).

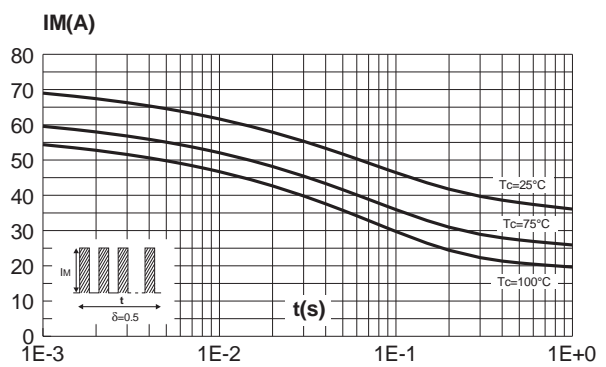


Fig. 4-3: Non repetitive surge peak forward current versus overload duration (TO-220FPAB).

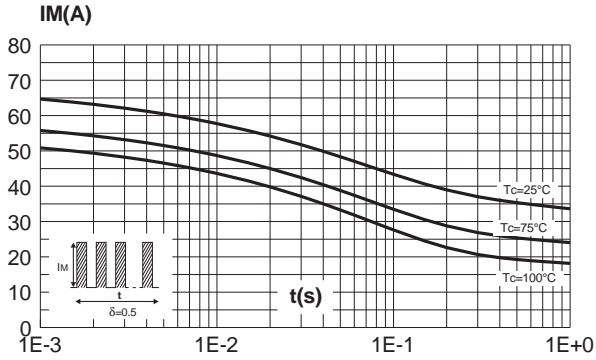


Fig. 5-1: Relative variation of thermal impedance junction to case versus pulse duration (D²PAK, TO-220AB).

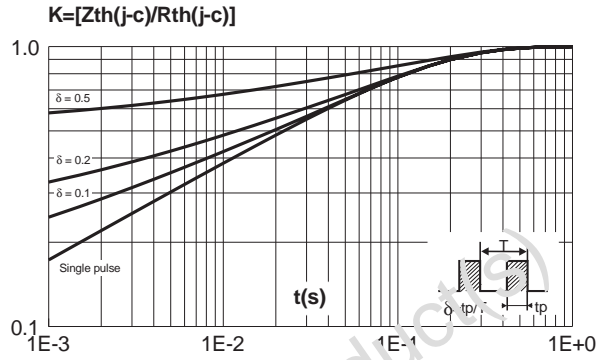


Fig. 5-2: Relative variation of thermal impedance junction to case versus pulse duration (ISOWATT220AB, TO-220FPAB).

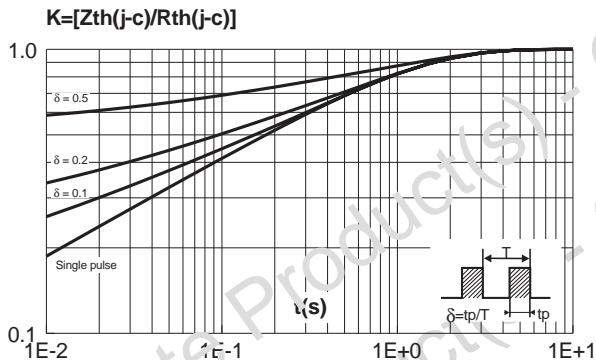


Fig. 6: Forward voltage drop versus forward current (maximum values, per diode).

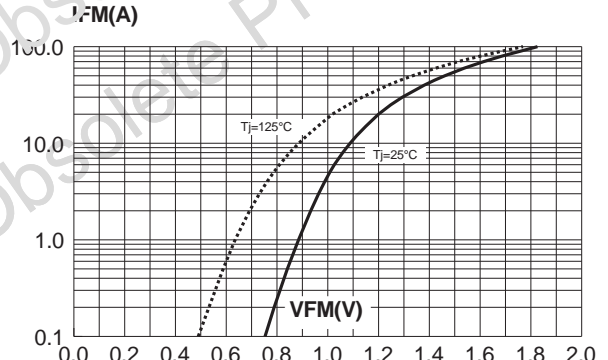


Fig. 7: Junction capacitance versus reverse voltage applied (typical values, per diode).

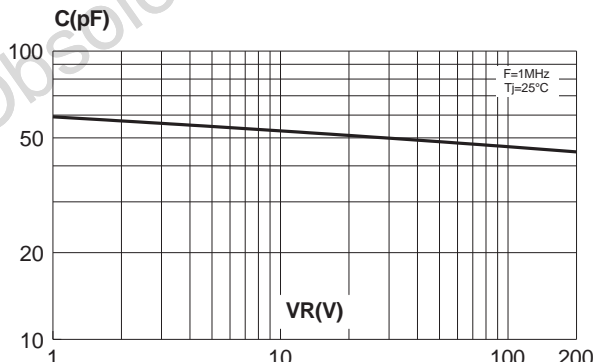


Fig. 8: Reverse recovery charges versus dIF/dt (per diode).

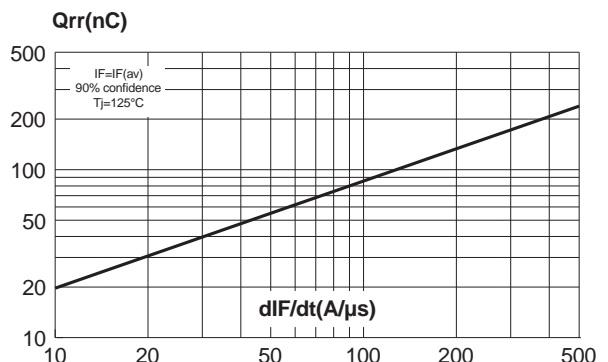


Fig. 9: Peak reverse recovery current versus dI_F/dt (per diode).

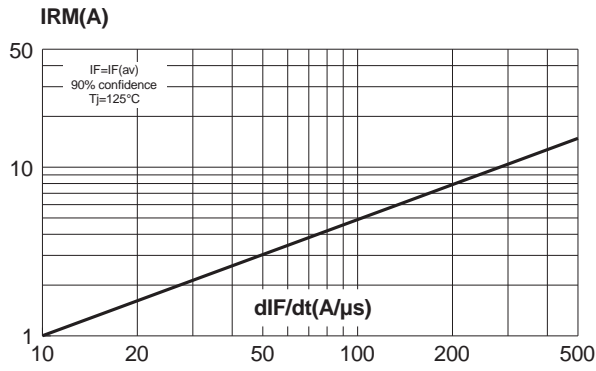


Fig. 10: Dynamic parameters versus junction temperature.

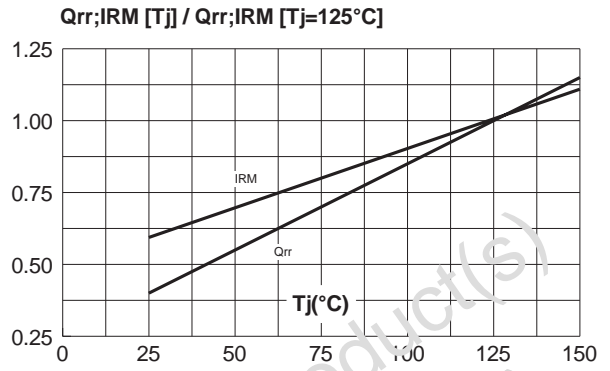
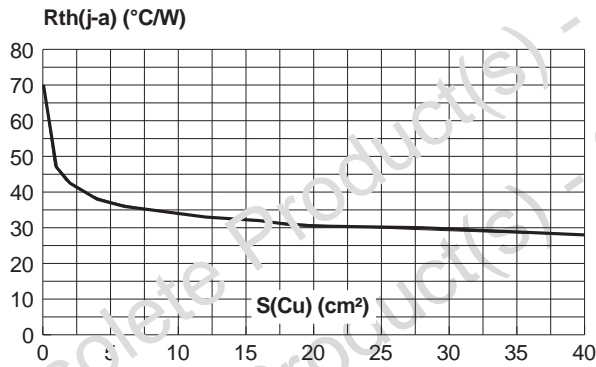
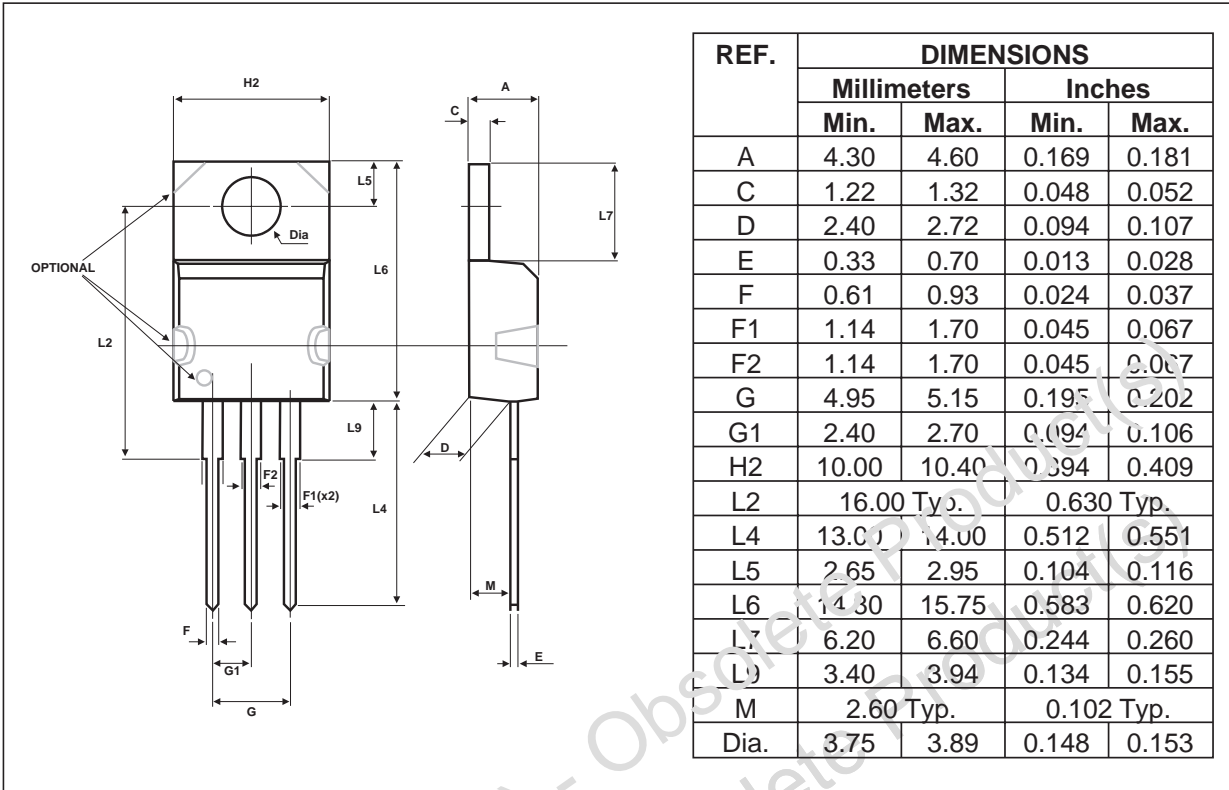


Fig. 11: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35μm) (D²PAK).

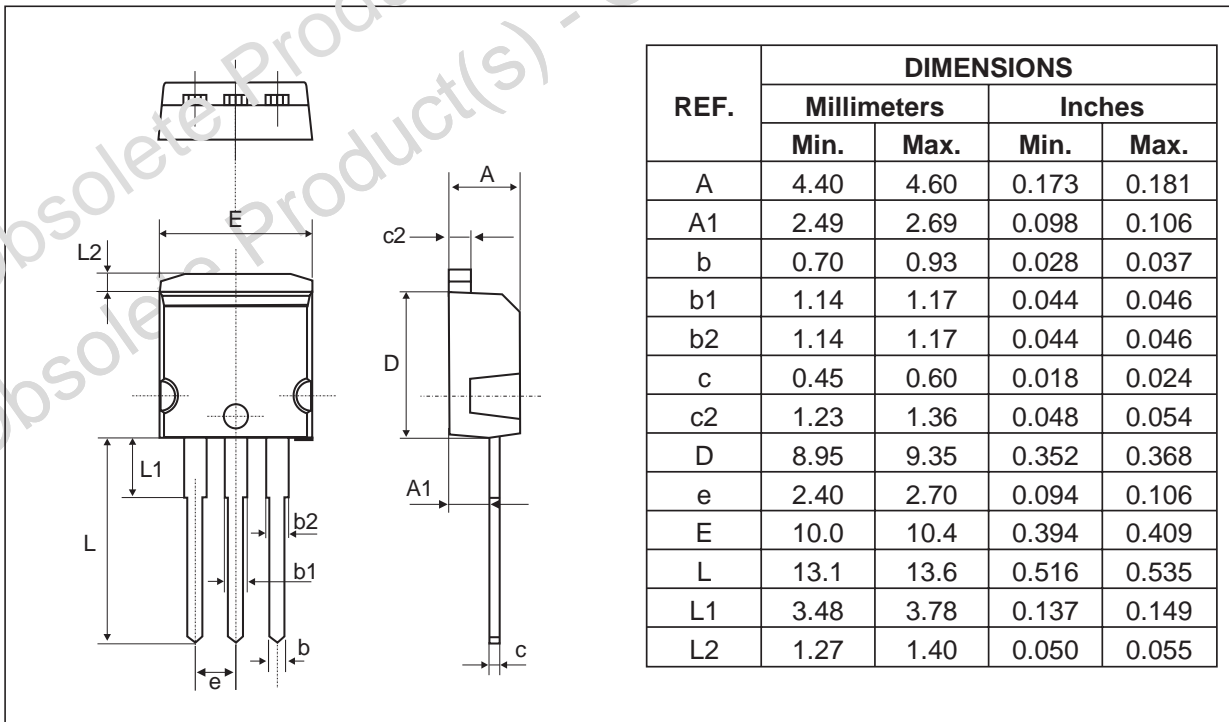


Obsolete Product(s) - Obsolete Product(s)

PACKAGE MECHANICAL DATA
TO-220AB (JEDEC compatible)

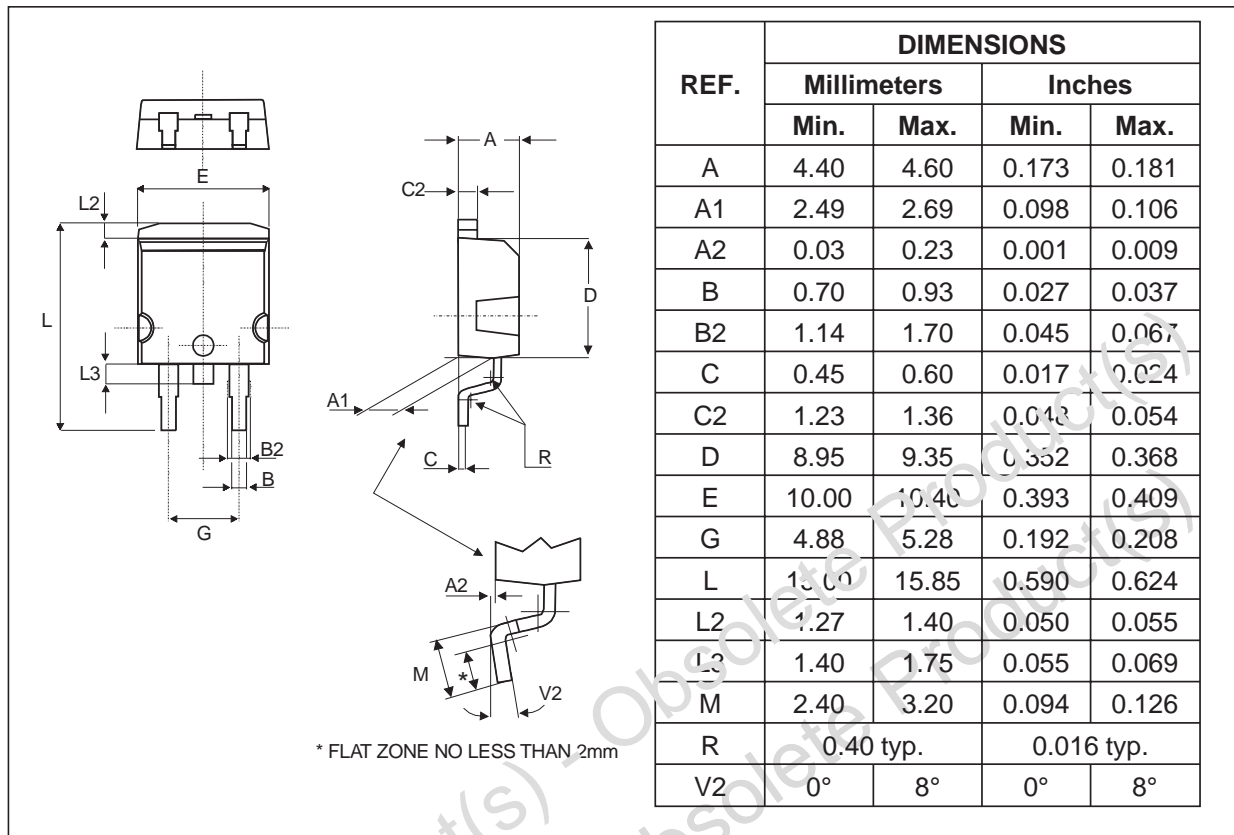


PACKAGE MECHANICAL DATA
I²PAK

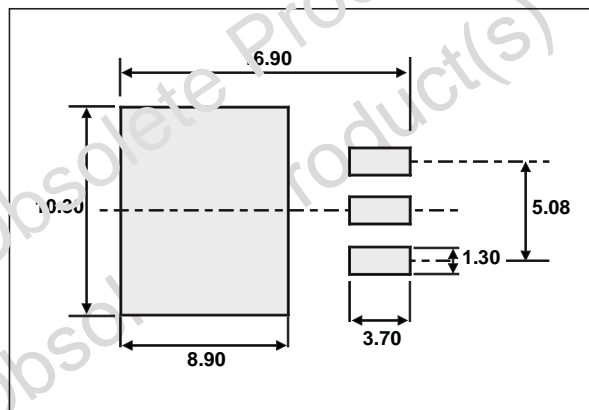


BYW51/F/G/FP/R-200

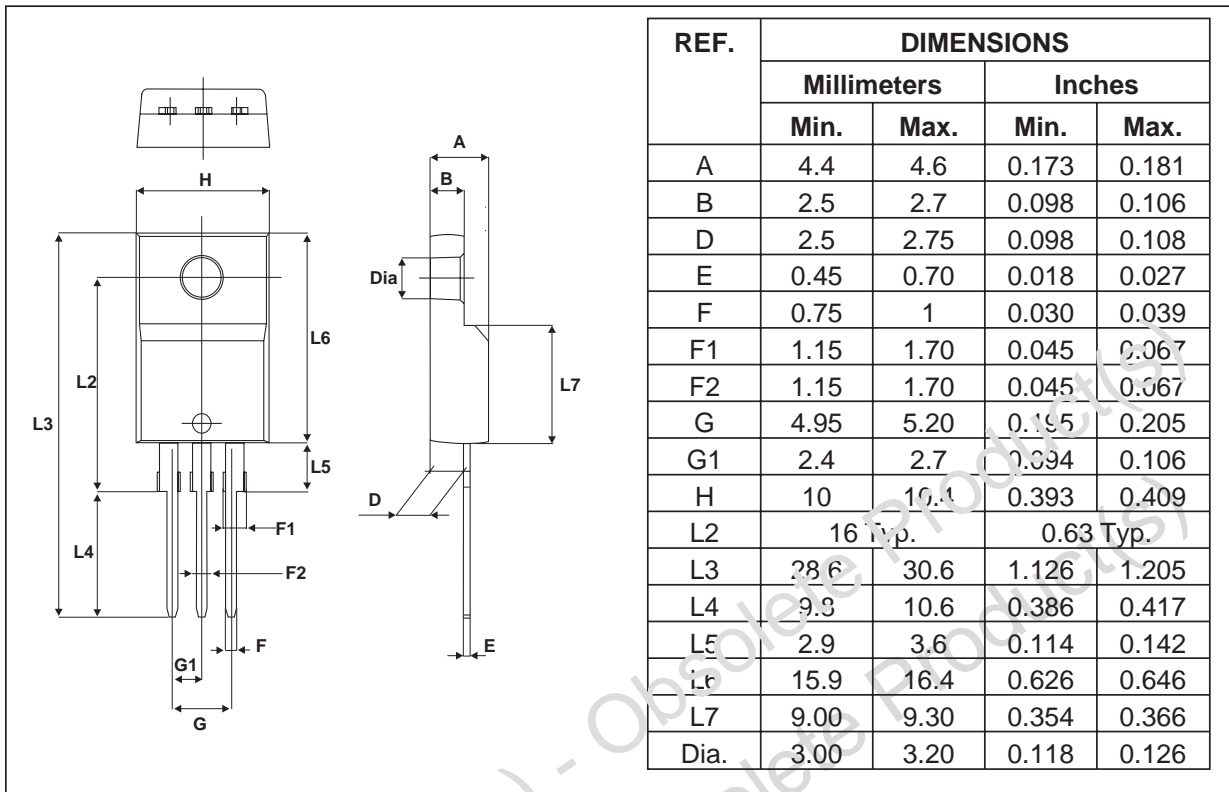
PACKAGE MECHANICAL DATA
D²PAK



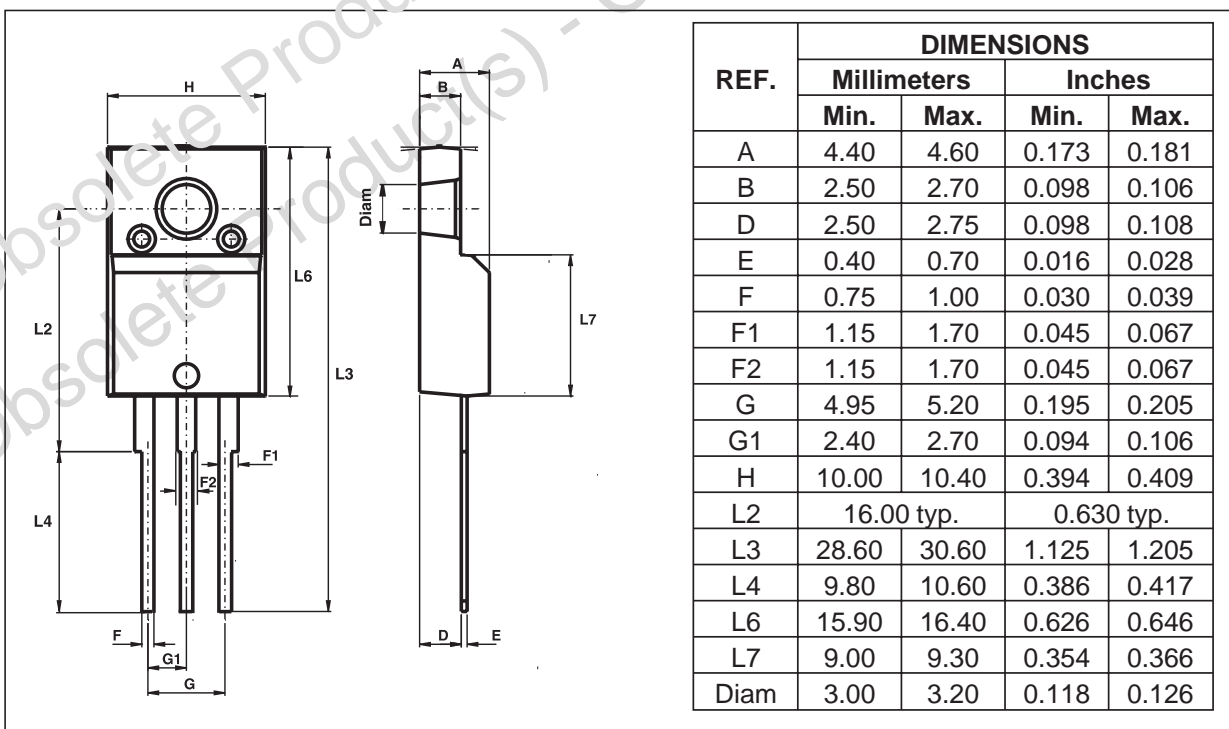
FOOT PRINT (in millimeters)
D²PAK



PACKAGE MECHANICAL DATA
TO-220FPAB



PACKAGE MECHANICAL DATA
ISOWATT220AB (JEDEC compatible)



| Ordering code | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|-------------|--------------------|---------|----------|---------------|
| BYW51-200 | BYW51-200 | TO220AB | 2.2 g. | 50 | Tube |
| BYW51F-200 | BYW51F-200 | ISOWATT220AB | 2.08 g. | 50 | Tube |
| BYW51G-200 | BYW51G-200 | D ² PAK | 1.48 g. | 50 | Tube |
| BYW51FP-200 | BYW51FP-200 | TO-220FPAB | 2g | 50 | Tube |
| BYW51R-200 | BYW51R-200 | I ² PAK | 1.49 g | 50 | Tube |

- Recommended torque value (TO-220AB): 0.8 N.m.
- Maximum torque value (TO-220AB): 1.0 N.m.
- Recommended torque value (ISOWATT220AB / TO-220FPAB): 0.55 N.m.
- Maximum torque value (ISOWATT220AB / TO-220FPAB): 0.70 N.m.
- Epoxy meets UL94,V0

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